

HD74LV1GW16A

Dual Buffer R04DS0032EJ0300
Rev.3.00
Jan 10, 2014

Description

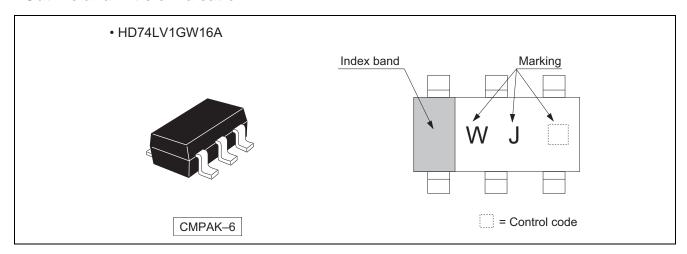
The HD74LV1GW16A has dual buffer in a 6 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.65 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LV1GW16ACME	CMPAK-6 pin	PTSP0006JA-A (CMPAK-6V)	СМ	E (3,000 pcs / Reel)

Outline and Article Indication

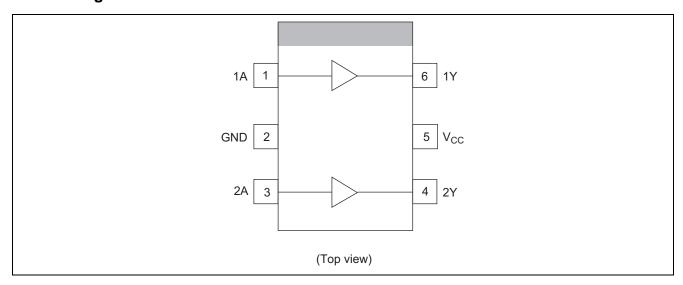


Function Table

Input A	Output Y			
Н	Н			
L	L			

H : High level L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to 7.0	V	
Output voltage range *1, 2	1/	-0.5 to $V_{CC} + 0.5$	V	Output : H or L
Output voltage range	Vo	-0.5 to 7.0	v	V _{CC} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	Io	±25	mA	$V_O = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{CC}	1.65	5.5	V	
Input voltage range	VI	0	5.5	V	
Output voltage range	Vo	0	V _{CC}	V	
		_	1		V _{CC} = 1.65 to 1.95 V
	١,	_	2		$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
	I _{OL}	_	6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
Output ourront		_	12	mA	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Output current		_	-1		V _{CC} = 1.65 to 1.95 V
	I _{OH}	_	-2		V _{CC} = 2.3 to 2.7 V
		_	-6		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		V _{CC} = 4.5 to 5.5 V
		0	300		V _{CC} = 1.65 to 1.95 V
Input transition rise or fall rate	A4 / Ax	0	200	70 / //	V _{CC} = 2.3 to 2.7 V
Input transition rise or fall rate	Δt / Δv	0	100	ns / V	V _{CC} = 3.0 to 3.6 V
		0	20		V _{CC} = 4.5 to 5.5 V
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{CC} (V) *	Min	Тур	Max	Unit	Test condition
		1.65 to 1.95	V _{CC} ×0.75		_		
		2.3 to 2.7	V _{CC} ×0.7	_	_		
	V _{IH}	3.0 to 3.6	V _{CC} ×0.7		_		
Innut voltogo		4.5 to 5.5	V _{CC} ×0.7	_	_	V	
Input voltage		1.65 to 1.95	_	_	V _{CC} ×0.25	V	
		2.3 to 2.7	_	_	V _{CC} ×0.3		
	V _{IL}	3.0 to 3.6	_	_	V _{CC} ×0.3		
		4.5 to 5.5	_	_	V _{CC} ×0.3		
		1.8	_	0.25	_		
Liveteresia veltare	.,	2.5	_	0.30	_	V	$V_T^+ - V_T^-$
Hysteresis voltage	V _H	3.3	_	0.35	_	V	VT - VT
		5.0	_	0.45	_		
		Min to Max	V _{CC} -0.1	_	_		I _{OH} = -50 μA
		1.65	1.4	_	_		I _{OH} = -1 mA
	V_{OH}	2.3	2.0	_	_		I _{OH} = -2 mA
		3.0	2.48	_	_		I _{OH} = -6 mA
Output valtage		4.5	3.8	_	_	V	I _{OH} = -12 mA
Output voltage		Min to Max	_	_	0.1	V	I _{OL} = 50 μA
		1.65	_	_	0.3		I _{OL} = 1 mA
	V_{OL}	2.3	_	_	0.4		I _{OL} = 2 mA
		3.0	_	_	0.44		I _{OL} = 6 mA
		4.5	_	_	0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	V _{IN} = 5.5 V or GND
Quiescent supply current	I _{CC}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I _{OFF}	0	_	_	5	μΑ	$V_1 \text{ or } V_0 = 0 \text{ to } 5.5 \text{ V}$
Input capacitance	C _{IN}	3.3	_	3.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

 $V_{CC}=1.8\pm0.15\ V$

Item	Symbol		$T_a = 25^{\circ}C$ $T_a = -40 \text{ to } 85^{\circ}C$		to 85°C	Unit	Test	FROM	то	
item	Syllibol	Min	Тур	Max	Min	Max	Oill	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	11.6	20.0	1.0	22.0		C _L = 15 pF	^	V
delay time	t _{PHL}	_	18.6	30.4	1.0	33.0	ns	C _L = 50 pF	A	r

 $V_{CC}=2.5\pm0.2\ V$

Item	Symbol		T _a = 25°C	$T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	ТО	
item	Syllibol	Min	Тур	Max	Min	Max	Onit	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	7.0	11.7	1.0	14.0	ns	C _L = 15 pF	А	Υ
delay time	t _{PHL}	_	10.5	15.5	1.0	18.0		C _L = 50 pF		

 $V_{CC}=3.3\pm0.3~V$

Item	Symbol		T _a = 25°C		$T_a = -40$	to 85°C	Unit	Test	FROM	то
item	Syllibol	Min	Тур	Max	Min	Max	Onic	Conditions	(Input)	(Output)
Propagation	t _{PLH}		5.0	7.1	1.0	8.5		C _L = 15 pF	_	V
delay time	t _{PHL}		7.5	10.6	1.0	12.0	ns	C _L = 50 pF	A	Ť

 $V_{CC} = 5.0 \pm 0.5~V$

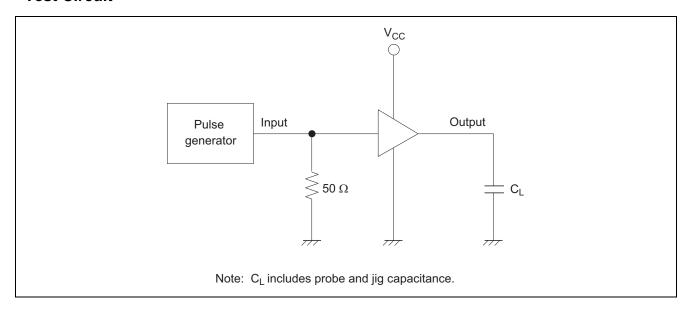
Itam	Symbol		$T_a = 25^{\circ}C$ $T_a = -40 \text{ to } 85^{\circ}C$		Unit	Test	FROM	ТО		
Item	Syllibol	Min	Тур	Max	Min	Max	Oill	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	3.8	5.5	1.0	6.5		C _L = 15 pF	^	V
delay time	t _{PHL}	_	5.3	7.5	1.0	8.5	ns	C _L = 50 pF	Α .	1

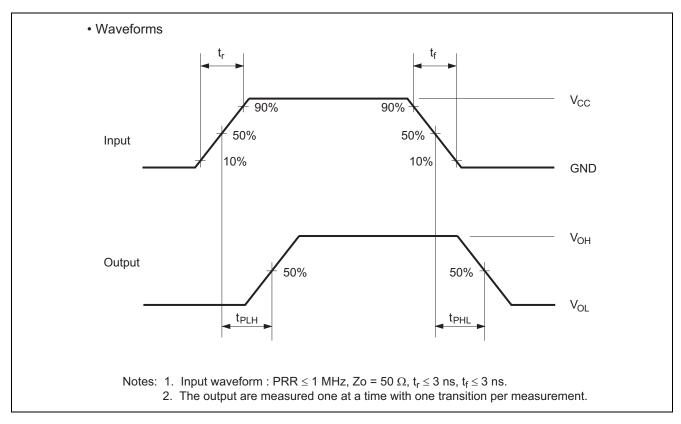
Operating Characteristics

 $C_L = 50 \text{ pF}$

Item	Cumbal	V 00	T _a = 25°C			Unit	Test Conditions	
item	Symbol	V _{CC} (V)	Min	Тур	Max	Onic	rest Conditions	
Power dissipation	_	3.3	_	8.5	_	~F	f = 10 MHz	
capacitance	CPD	5.0	_	10.0	_	рF		

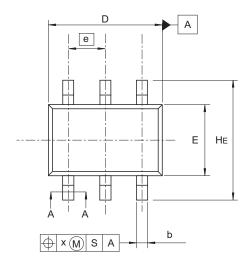
Test Circuit

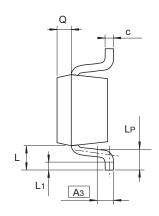


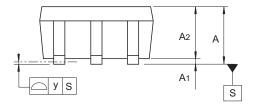


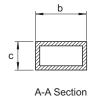
Package Dimensions

JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
SC-88	PTSP0006JA-A	CMPAK-6 / CMPAK-6V	0.006









Reference	Dimensi	ons in mi	llimeters	
Symbol	Min	Nom	Max	
Α	0.8	_	1.1	
A ₁	0	_	0.1	
A ₂	0.8	0.9	1.0	
A ₃	_	0.25	_	
b	0.15	0.2	0.25	
С	0.1	0.15	0.25	
D	1.8	2.0	2.2	
E	1.15	1.25	1.35	
е	_	0.65	_	
HE	2.0	2.1	2.2	
L	0.3		0.7	
L ₁	0.1		0.5	
L _P	0.2		0.6	
Х			0.05	
у			0.05	
Q	_	0.25	_	

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